Detailed Curriculum Vitae

Prof. Dr. Sefer Bora Lisesivdin, BSc (Engineering), MSc, PhD, SMIEEE



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CONTACT INFORMATION

(1) Department of Physics

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Personal web: http://sblisesivdin.github.io
Group web: http://www.lrgresearch.org

EDUCATION

Ph.D.	Physics,	Gazi	University,	Ankara,	Turkey
Dissertat	ion: Electro	n and Mag	neto Transport	Properties of	AlGaN/GaN
Based	High	Electron	Mobility	Transistors	(HEMTs)
Advisor:	Prof. Dr. M	ehmet Kasap)		
M.Sc. Ac	dvanced Tec	hnologies, G	azi University, A	Ankara, Turke	у
Thesis:	Transport	Properties	of InGaAs/G	aAs and A	AlGaAs/GaAs
Semicon	ductors Grov	wn by MBE			
Advisor:	Assoc. Prof	Dr. Mehme	et Kasap		
B.Sc (En	g). Physics I	Engineering,	Hacettepe Unive	ersity, Ankara	Turkey
Senior Pr	roject: Devel	lopment of X	K-Ray Data Anal	ysis Software	for Windows
Systems					
	Dissertat Based Advisor: M.Sc. Ad Thesis: Semicon Advisor: B.Sc (En Senior Pr	Dissertation: Electron Based High Advisor: Prof. Dr. M. M.Sc. Advanced Tec. Thesis: Transport Semiconductors Grown Advisor: Assoc. Prof. B.Sc (Eng.). Physics I. Senior Project: Deve.	Dissertation: Electron and Mag Based High Electron Advisor: Prof. Dr. Mehmet Kasar M.Sc. Advanced Technologies, Control Thesis: Transport Properties Semiconductors Grown by MBE Advisor: Assoc. Prof. Dr. Mehmed B.Sc (Eng). Physics Engineering, Senior Project: Development of St	Dissertation: Electron and Magneto Transport Based High Electron Mobility Advisor: Prof. Dr. Mehmet Kasap M.Sc. Advanced Technologies, Gazi University, A Thesis: Transport Properties of InGaAs/G Semiconductors Grown by MBE Advisor: Assoc. Prof. Dr. Mehmet Kasap B.Sc (Eng). Physics Engineering, Hacettepe University Senior Project: Development of X-Ray Data Anal	Dissertation: Electron and Magneto Transport Properties of Based High Electron Mobility Transistors Advisor: Prof. Dr. Mehmet Kasap M.Sc. Advanced Technologies, Gazi University, Ankara, Turke Thesis: Transport Properties of InGaAs/GaAs and Asemiconductors Grown by MBE Advisor: Assoc. Prof. Dr. Mehmet Kasap B.Sc (Eng). Physics Engineering, Hacettepe University, Ankara Senior Project: Development of X-Ray Data Analysis Software

RESEARCH INTERESTS

Experimental and numerical (with calculating self-consistent solutions of Schroedinger-Poisson equations) investigation of electron and magnetotransport properties, strain, persistent photoconductivity, hot-electron transport properties, Shubnikov de Hass parameters and quantum parameters of 2 dimensional gas (2DEG) of III-V group semiconductor materials including, GaAs, GaN, InGaN, TiO₂ bulks and AlGaN/GaN, AlGaN/(AlN)/GaN, AlGaN/(AlN)/GaN, AlGaN/(AlN)/GaN/AlN and AlInN/AlN/InGaN/AlN heterostructures, MgZnO/ZnO, BeZnO/ZnO heterostructures.

Ab initio calculations of wide band gap semiconductors MgO, GaN, MgZnO, diamond and low dimensional structures like graphene, graphene nanoribbons, black phosphorus, 2D structures with kagome lattice structure.

Optical properties and ODMR measurements of NV- centers in Diamond.

SCHOLARSHIPS / FELLOWSHIPS / AWARDS

2019	Leaders in Innovation Fellowship, Royal Academy of Engineering,			
	United Kingdom,			
2017	Duty Award, Gazi University Faculty of Science, Ankara, Turkey.			
2016	Turkish Academy of Sciences, Distinguished Young Scientist Award			
2015	IEEE Senior Membership			
2015	SCI-indexed Publication Award, Gazi University, Ankara, Turkey.			
2015	Duty Award, Gazi University Faculty of Science, Ankara, Turkey.			
2014	Turkish Physical Union Prof. Dr. Sevket Erk Outstanding Young			
	Scientist Award.			
2014	SCI-indexed Publication Award, Gazi University, Ankara, Turkey.			
2014	SCI-indexed Citation Award, Gazi University, Ankara, Turkey.			
2013	TUBITAK 2219 scholarship for postdoc research (6 months).			
2007-present	20 publications are promoted through TUBITAK Incentive Program for			
	International Scientific Publications.			
2010, 2012	SCI-indexed Publication Award, Gazi University, Ankara, Turkey.			
2008-2009	Postdoc fellowship for postdoc studies.			
2007-2008	TUBITAK 2214 scholarship for PhD research (6 months).			
2007	Progetto Lagrange PhD Scholarship, Politechnico di Torino, Italy (not used			
	due to family issues).			
2005-2008	Several project scholarship for M.Sc. and Ph.D. studies.			

GRANTS & PROJECT MEMBERSHIPS

Earned grants as a project investigator (PI) or project co-investigator (co-PI)

2018-2019	TUBITAK 1512, 2180227, Production of Compact USB Fiber-coupled UV-VIS-NIR Optical Spectrometer for Industrial and Scientific Purposes, CEO and PI, Budget, 149 846 TL no-return grant (approximately 24 500 Euros)
2017-2020	TUBITAK 1001,116F197, Investigation of Growth Behaviors and 2DEG
	Properties of of MgZnO/ZnO Heterostructures grown by USPECVD
	Method, PI, Budget, 359 810 TL (approximately 88 600 Euros)
2014-2016	Joint grant of Scientific and Technological Research Council of Turkey and
	RFBR of Russia, 113F364, Manipulation properties of two-dimensional
	electronic gas using insitu surface passivation of AlGaN/GaN
	heterostructures by molecular beam epitaxy, PI, Budget: 282 910 TL
	(approximately 97 500 Euros)
2012-2013	University Research Grant, 05-2012/13, Numerical optimization of Mg _x Zn ₁ -
	_x O/ZnO and Be _x Zn _{1-x} O/ZnO based heterostructure transistors, PI, Budget: 14
	889 TL (approximately 6 500 Euros)
2012-2013	University Research Grant, 05-2012/14, Investigation of the effects of
	transition metal palladium on electronical, structural and optical properties of
	graphene nanoribbons, PI, Budget: 14 955 TL (approximately 6 500 Euros)
	(41)

Project memberships

TUBITAK 1002 Support Project, 209T051, MOVPE growth and 2010-2012 characterization of epitaxial germanium for infrared photovoltaic and sensor applications, Researcher, Budget: 25k TL (approximately 11k Euros)

2009-2012	TUBITAK 1007 Research Project, 107A012, Researcher, Budget: 4.7 M TL (approximately 2M Euros)
2008-2012	Military Related Research Project, SAVS020, Scholar, Budget: 5.8M TL
	(approximately 2 5M Euros)
2008-2010	TUBITAK 1001 Research Project, 108T018, Epitaxial growth and
	characterization of infrared AlGaAs laser diode materials, Scholar, Budget:
	358 400 TL (approximately 156k Euros)
2008-2010	TUBITAK (Turkey) - ANCS (Romania) Joint Research Project, TBAG-
	U/220 (107A584), Studies on synthesis and characterization of TiO2 thinfilm
	nanostructures which have applications in ecological physics, Scholar,
	Budget: 58k TL (approximately 25k Euros)
2006-2009	Military Related Research Project, SAVM005, Researcher, Budget: 4.7 M
	TL (approximately 2M Euros)
2006-2007	TUBITAK 1007 Research Project, 105A005, Scholar, Budget: 5.5M TL
	(approximately 2 4M Euros)

PROFESSION	IAL APPOINTMENTS
2019-2020	Visiting Researcher, Institute for Quantum Optics, University of Ulm, Ulm,
	Germany (3 months)
2018-cont.	Full Professor, Department of Physics, Faculty of Science, Gazi University,
	Ankara Turkey
2013	Visiting Researcher, School of Computer Science and Electronics
	Engineering, University of Essex, Colchester, UK.
2011-2018	Associate Professor, Department of Physics, Faculty of Science, Gazi
	University, Ankara Turkey
2009-2011	Assistant Professor, Department of Physics, Faculty of Science and Arts,
	Gazi University, Ankara Turkey
2008-2009	Post-doctoral Researcher, Nanotechnology Research Center, Bilkent
	University, Ankara, Turkey http://www.nanotam.bilkent.edu.tr

RESEARCH EXPERIENCE

2019-2020	Visiting Researcher, Institute for Quantum Optics, University of Ulm, Ulm,
	Germany (3 months)
2013	Visiting Researcher, Department of Computing and Electronic Systems
	University of Essex, Colchester, UK (6 months)
2008-2009	Post-doctoral Researcher, Nanotechnology Research Center, Bilkent
	University, Ankara, Turkey http://www.nanotam.bilkent.edu.tr
2007-2008	Research Student, Department of Computing and Electronic Systems
	University of Essex, Colchester, UK (6 months)

TEACHING EXPERIENCE

These courses correspond to a number of more than 2300 students as of this CV's writing time.

Institute of Scie	ence, Gazi University, Ankara, Turkey
2020/1	Instructor, Fiz 5026 Physics of Low-dimensional Semiconductors
2020/1	Instructor, Fiz 5024 Micro and Nanofabrication Methods
2019/2	Instructor, Fiz 522 Micro and Nanofabrication Methods
2018/2	Instructor, Fiz 522 Micro and Nanofabrication Methods
2018/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
2017/2	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
2017/2	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
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2017/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
2016/2	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
2016/2	Instructor, Fiz 522 Micro and Nanofabrication Methods
2016/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
2015/2	Instructor, Fiz 522 Micro and Nanofabrication Methods
2015/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
2014/2	Instructor, Fiz 522 Micro and Nanofabrication Methods
2014/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
2013/2	Instructor, Fiz 522 Micro and Nanofabrication Methods
2013/2	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
2013/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
2013/1	Instructor, Fiz 524 Physics of Low-dimensional Semiconductors
2012/1	Instructor, Fiz 522 Micro and Nanofabrication Methods
Faculty of Scie	nce, Gazi University, Ankara, Turkey
2020/1	Instructor, Fiz 1123 Introduction to Nanotechnology
2018/1	Instructor, Fiz 123 Introduction to Nanotechnology
2017/1	Instructor, Fiz 123 Introduction to Nanotechnology
2016/1	Instructor, Fiz 123 Introduction to Nanotechnology
2015/1	Instructor, Fiz 123 Introduction to Nanotechnology
2014/2	Advisor, Fiz 414 Research Project
2014/1	Advisor, Fiz 413 Research Project
2014/1	Instructor, Fiz 123 Introduction to Nanotechnology
2013/1	Advisor, Fiz 413 Research Project
2013/1	Advisor, Fiz 413 Research Project (2 students)
2012/1	Instructor, Enf 102 Basic Computer Usage and Fortran Language (2 groups)
2011/2	Advisor, Fiz 414 Research Project
• •	nce and Arts, Gazi University, Ankara, Turkey
2018/2	Advisor, Fiz 414 Research Project
2018/1	Advisor, Fiz 413 Research Project
2011/1	Advisor, Fiz 413 Research Project
2009/2	Advisor, Fiz 414 Research Project (2 students)
2009/1	Advisor, Fiz 413 Research Project (2 students)
Faculty of Eng	ineering, Gazi University, Ankara, Turkey
2016/2	Instructor, Fiz 104, Physics II (2 groups)
2015/2	Instructor, Fiz 104, Physics II (2 groups)

2014/2	Instructor, Fiz 104, Physics II (2 groups)
2013/2	Instructor, Fiz 104, Physics II (4 groups)
2013/1	Instructor, Fiz 103 Physics I (3 groups)
2012/1	Instructor, Fiz 103 Physics I (2 groups)
2011/2	Instructor, Fiz 156 Physics Lab. (Mechanics)
2011/2	Instructor, Fiz 104, Physics II (3 groups)
2011/1	Instructor, Fiz 103 Physics I (3 groups)
2009/2	Instructor, Fiz 156 Physics Lab. (Mechanics)
2009/2	Instructor, Fiz 104, Physics II (2 groups)

Faculty of Dentistry, Gazi University, Ankara, Turkey

2012/1 Instructor, Fzk 111 Physics.

Faculty of Science at Polatlı, Gazi University, Polatlı, Ankara, Turkey

2012/1 Instructor, Fiz 315 Properties of Matter.

Faculty of Technology, Gazi University, Ankara, Turkey 2020/1 Instructor, Fiz 103, Physics II (2 groups) 2019/2 Instructor, Fiz 104, Physics II (2 groups) 2018/2 Instructor, Fiz 104, Physics II 2017/2 Instructor, Fiz 104, Physics II 2014/1 Instructor, Fiz 101 Physics I (2 groups). 2011/1 Instructor, Fiz 101 Physics I.

Faculty of Technical Education, Gazi University, Ankara, Turkey

2011/1 Instructor, Fiz 101 Physics I. 2009/2 Instructor, Fiz 102 Physics II.

2009/1 Instructor, Fiz 101 Physics I (4 groups).

Turkish Military Academy, National Defense University, Ankara, Turkey

2018-2019 Instructor, Physics.

PROFESSIONAL ACTIVITIES

2019	Scientific Committee Member, VIII. ADIM Physics Days, 12-15 September,
	Bilecik, Turkey.
2018	Scientific Committee Member, VII. ADIM Physics Days, 23-25 May, Aydin,
	Turkey.
2017	Scientific Committee Member, VI. ADIM Physics Days, 19-21 July,
	Balikesir, Turkey.
2015	Scientific Committee Member, 1st International Conference on Organic
	Electronic Material Technologies (OEMT-2015) 25-28 March Elazig,
	Turkey.
2015	Scientific Committee Member, 2nd International Nanoscience and
	Nanotechnology for Next Generation (NaNoNG) 29-31 October Antalya,
	Turkey.
2011-2014	Member of board of management of the Photonics Research Center at Gazi
	University, Ankara, Turkey. http://fotonik.gazi.edu.tr
2004	Member of organizing group of 11th Condensed Matter Ankara Meeting at
	Gazi University, Ankara, Turkey.

PROFESSIONAL SERVICES

Editorial Board Member

- PLOS ONE (*SCI-indexed*) (2013-2016, 2019-continue)
- Advances in Condensed Matter Physics (SCI-indexed) (2019-continue)
- Advances in OptoElectronics (ESCI-indexed) (2019)

Issue Editor (SCI-indexed) (2016)

- Advances in Materials Science and Technology "Recent Progress in Group III-Nitride Electronic and Optoelectronic Devices"

Reviewer (SCI-indexed) (PUBLONS: https://publons.com/researcher/2891039/sefer-bora-lisesivdin/)

- Journal of Physics and Chemistry of Solids
- Journal of Physics D Applied Physics,
- Semiconductor Science and Technology,
- Superlattices and Microstructures,
- Journal of Materials Science: Materials in Electronics
- Journal of Materials Science: Materials in Electronics
- Nanotechnology,
- Diamond and Related Materials,
- Applied Physics Letters,
- Physica E: Low-dimensional Systems and Nanostructures,
- Physica B: Condensed Matter,
- AIP Advances.
- Computational Materials Science,
- Synthetic Metals,

PROFESSIONAL AFFILIATIONS

2005-present Senior Member, II	EEE ((Institute of E	electrical a	and Electronics	Engineers)
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2005-present Senior Member, IEEE Electron Devices Society

2006 Member, IEEE Communications Society

2006 Member, SPIE (Society of Photographic Instrumentation Engineers)

Member, Hacettepe University Alumni

SEMINARS

02/2008

12/2014	"Elektriksel Olarak Pompalanan Seyreltik Azotlu Dikey Kaviteli Yarıiletken

Optik Yükselteç" Physics Department, Istanbul University, Istanbul, Turkey.

05/2008 "AlGaN/GaN-temelli Yüksek Elektron Hareketliliğine Sahip Transistörlerin

(HEMTs) Elektron ve Manyeto-iletim Özelliklerinin İncelenmesi (in

Turkish)", Department of Physics, Akdeniz University, Antalya, Turkey.

"Investigation of 2DEG parameters in AlGaN/GaN based heterostructures

using QMSA technique" Department of Computing and Electronic Systems,

University of Essex, Colchester, UK.

ATTENDED COURSES AND WORKSHOPS

01/2006 I. Adaligeli, "Solid State Educational Workshop 2006.1: The Theory of Spin

Transport (1 Week)" Feza Gürsey Institute, Istanbul, Turkey.

J. Schliemann, "Solid State Educational Workshop 2006.1: Rashba and 01/2006 Spin-Hall Effects in Quantum Dots (1 Week)" Feza Gürsey Institute, Istanbul, Turkey. E.V. Sukhorukov, "Solid State Educational Workshop 2006.1: The Physics 01/2006 of Quantum Shot Noise (1 Week)" Feza Gürsey Institute, Istanbul, Turkey. 03-04/2005 Gerhardts, "Solid State Educational Workshop 2004.3-2: Magnetotransport in low-dimensional systems (3 Weeks)", Bilkent University, Ankara, Turkey.

PUBLICATIONS

Cites and h-index

Index name	Total cite	h-index
Web of Science	778	15
Google Scholar	975	16

Books and Book Chapters

- 2 S. B. Lisesivdin, B. Sarikavak-Lisesivdin, E. Ozbay "Chapter 18: The Effects of the Interaction of Transition Metals on the Electronic Properties of the Graphene Nanosheets and Nanoribbons" Graphene Science Handbook Vol.3, CRCPress, Taylor&Francis, (2016).
- 1 E. L. Wolf, M. Medikonda, (Transl. eds: B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>) "Nanoteknoloji Devrimini Anlamak" Nobel Press, (2014).

SCI-Articles

- 72 F. Sonmez, S. Ardali, G. Atmaca, <u>S.B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "The effect of passivation layer, doping and spacer layer on electron-longitudinal optical phonon momentum relaxation time in Al_{0.3}Ga_{0.7}N/AlN/GaN heterostructures" *Mater. Sci. Semicond. Process.* **122**, 105449 (2021).
- 71 H. Hebal, Z. Koziol, <u>S.B. Lisesivdin</u>, R. Steed "General-purpose open-source 1D self-consistent Schrödinger-Poisson Solver: Aestimo 1D" *Comput. Mater. Sci.* **186**, 110015 (2021).
- **70** B.Sarikavak-Lisesivdin, <u>S.B.Lisesivdin</u>, E.Ozbay, F.Jelezko "Structural parameters and electronic properties of 2D carbon allotrope: Graphene with a kagome lattice structure" *Chem. Phys. Lett.* **760**, 138006 (2020).
- **69** E. Kutlu, P. Narin, A. Yildiz, <u>S. B. Lisesivdin</u> "Effects of Annealing under Different Atmospheres on Structural and Optical Properties of USCVD grown ZnO Nanostructures" *Mater. Sci. Eng. B* **254**, 114506 (2020).
- **68** R. Ibrahem, P. Narin, <u>S. B. Lisesivdin</u>, E. Ozbay "Investigation of electronic and optical properties of wurtzite MgZnO using GGA + U formalism", *Philos. Mag. Lett.* **99**, 424 (2019).

- 67 P. Narin, J. M. All Abbas, G. Atmaca, E. Kutlu, <u>S. B. Lisesivdin</u>, E. Ozbay "Ab initio study of electronic properties of armchair graphene nanoribbons passivated with heavy metal elements" *Solid State Commun.* **296**, 8 (2019).
- **66** P. Narin, E. Arslan, M. Ozturk, M. Ozturk, <u>S. B. Lisesivdin</u>, E. Ozbay "Scattering analysis of ultrathin barrier (< 7 nm) GaN-based heterostructures" *Appl. Phys. A: Mater. Sci. Process.* **125**, 278 (2019).
- **65** J. M. All Abbas, P. Narin, E. Kutlu, <u>S. B. Lisesivdin</u>, E. Ozbay "Electronic properties of Zigzag ZnO nanoribbons with Hydrogen and Magnesium passivations" *Physica B* **556**, (2019).
- **64** J.-H. Lee, J.-M. Ju, G. Atmaca, J.-G. Kim, S.-H. Kang, Y. S. Lee, S.-H. Lee, J.-W. Lim, H.-S. Kwon, S. B. Lisesivdin, J.-H. Lee "High Figure-of-Merit (V2BR/RON) AlGaN/GaN Power HEMT With Periodically C-Doped GaN Buffer and AlGaN Back Barrier" *IEEE J. Electron Dev. Soc.* **6**, 1179 (2018).
- 63 Ö. Ömeroğlu, E. Kutlu, P. Narin, S. B. Lisesivdin, E. Ozbay "Electronic Properties of Graphene Nanoribbons Doped with Zinc, Cadmium, Mercury Atoms" *Physica E* **104**, 124 (2018).
- **62** G. Atmaca, P. Narin, E. Kutlu, T. V. Malin, V. G. Mansurov, K. S. Zhuravlev, <u>S. B. Lisesivdin</u>, E. Ozbay, "Negative Differential Resistance Observation and a New Fitting Model for Electron Drift Velocity in GaN-Based Heterostructures" *IEEE Trans. Electron Dev.* **65**, 950 (2018).
- **61** P. Narin, E. Kutlu, G. Atmaca, A. Atilgan, A. Yildiz. <u>S. B. Lisesivdin</u>, "Structural and optical properties of hexagonal ZnO nanostructures grown by ultrasonic spray CVD" *Optik* **168**, 86 (2018).
- **60** E. Kutlu, P. Narin, <u>S. B. Lisesivdin</u>, E. Ozbay "Electronic and optical properties of black phosphorus doped with Au, Sn and I atoms" *Philos. Mag.* **98**, 155 (2018).
- **59** P. Narin, E. Kutlu, G. Atmaca, <u>S. B. Lisesivdin</u>, E. Ozbay "A first principles investigation of the effect of aluminum, gallium and indium impurities on optical properties of β-Si₃N₄ structure" *Optik* **147**, 115 (2017).
- **58** J. M. Al Abbas, P. Narin, G. Atmaca, E. Kutlu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "The effect of doping in different layers on 2DEG for ultrathin-barrier AlN/GaN heterostructures" *Optoelectron. Adv. Mater.-Rapid Comm.* **11**, 328 (2017).
- 57 J. M. All Abbas, G. Atmaca, P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "A Comparative Study of AlGaN and InGaN Back-Barriers in Ultrathin-Barrier AlN/GaN Heterostructures" *J. Elec. Mater.* 46, 5278 (2017).
- **56** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay "Electronic structure of β-Si3N4 crystals with substitutional icosagen group impurities" J. Optoelectron. Adv. Mater. 19, 278 (2017).

- **55** P. Narin, E. Kutlu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Özbay "Electronic properties of Li-doped zigzag graphene nanoribbons" *Physica E* **84**, 543 (2016).
- **54** E. Kutlu, P. Narin, G. Atmaca, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Özbay "Effect of substitutional As impurity on electrical and optical properties of β–Si3N4 Structure" *Mater. Res. Bull.* **83**, 128 (2016).
- **53** G. Atmaca, S. Ardali, E. Tiras, T. Malin, V. G. Mansurov, K. S. Zhuravlev, <u>S. B. Lisesivdin</u> "Scattering analysis of 2DEG mobility in undoped and doped AlGaN/AlN/GaN heterostructures with an *in situ* Si₃N₄ passivation layer" *Solid-State Electron.* **118**, 12 (2016).
- **52** I. Kara, Y. Sarikavak, <u>S. B. Lisesivdin</u>, M. Kasap "Evaluation of Morphological and Chemical Differences of Gunshot Residues in Different Ammunitions Using SEM/EDS Technique" *Environ. Foren.* **17**, 68 (2016).
- **51** G. Atmaca, P. Narin, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u> "Two Dimensional Electron Gas in a Hybrid GaN/InGaN/ZnO Heterostructure with Ultrathin InGaN Channel Layer" *Physica E* **79**, 67 (2016).
- **50** G. Atmaca, S. Ardali, P. Narin, E. Kutlu, <u>S. B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "Energy relaxation of hot electrons by LO phonon emission in AlGaN/AlN/GaN heterostructure with in situ Si3N4 passivation" *J. Alloys Compounds* **659**, 90 (2016).
- **49** S. Ardali, G. Atmaca, <u>S. B. Lisesivdin</u>, T. Malin, V. Mansurov, K. Zhuravlev, E. Tiras "The variation of temperature dependent carrier concentration and mobility in AlGaN/AlN/GaN heterostructure with SiN passivation" *Phys. Stat. Sol. B* **252**, 1960 (2015).
- **48** B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, N. Balkan, G. Atmaca, P. Narin, H. Cakmak, E. Ozbay "Energy relaxation of electrons in InGaN quantum wells" *Metall. Mater. Trans. A* **46**, 1565 (2015).
- **47** G. Atmaca, P. Narin, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, M. Kasap "Electron Transport Properties of Two Dimensional Electron Gas in Be_xZn_{1-x}O/ZnO Heterostructures" *Philos. Mag.* **95**, 79 (2015).
- **46** G. Atmaca, P. Tasli, G. Karakoc, E. Yazbahar and <u>S. B. Lisesivdin</u> "Numerical Investigation of the 2DEG Properties of AlGaN/AlN/GaN HEMT Structures with InGaN/GaN MQW Back-Barrier Structure" *Physica E* **65**, 110 (2015).
- **45** O. Donmez, F. Sarcan, <u>S. B. Lisesivdin</u>, M. P. Vaughan, A. Erol, M. Gunes, M. C. Arikan, J. Puustinen and M. Guina, "Analytic modeling of temperature dependence of 2D carrier mobility in as-grown and annealed GaInNAs/GaAs quantum well structures" *Semicond. Sci. Technol.* **29**, 125009 (2014).
- **44** <u>S. B. Lisesivdin</u>, G. Atmaca, E. Arslan, S. Cakmakyapan, O. Kazar, S. Butun, Jawad-ul-Hassan, E. Janzén and E. Ozbay "Extraction and scattering analyses of 2D and bulk carriers in epitaxial graphene-on-SiC structure" *Physica E* **63**, 87 (2014).

- **43** E. Arslan, S. Cakmakyapan, O. Kazar, S. Bütün, <u>S. B. Lisesivdin</u>, N. A. Cinel, G. Ertas, S. Ardali, E. Tiras, J. Ul-Hassan, E.Janzén and Ekmel Özbay "SiC substrate effects on electron transport in the epitaxial Graphene layer" *Electron. Mater. Lett.* **10**, 387 (2014).
- **42** <u>S. B. Lisesivdin</u>, N. A. Khan, S. Mazzucato, N. Balkan, M. J. Adams, V.-M. Korpijärvi, M. Guina, G. Mezosi and M. Sorel "Optical gain in 1.3 μm electrically-driven dilute nitride VCSOAs" *Nanoscale Res. Lett.* **9**, 22 (2014).
- **41** K. Elibol, G. Atmaca, P. Tasli, <u>S. B. Lisesivdin</u> "A Numerical Study on Subband Structure of InxAl1-xN/GaN-Based HEMT Structures with Low-Indium (x<0.10) Barrier Layer" *Solid State Commun.* **162**, 8 (2013).
- **40** A. F. Kuloglu, B. Sarikavak-Lisesivdin, <u>S. B. Lisesivdin</u>, E. Ozbay "First-principles calculations of Pd-terminated symmetrical armchair graphene nanoribbons" *Comp. Mater. Sci.* **68**, 18 (2013).
- **39** B. Sarikavak-Lisesivdin, S. B. Lisesivdin, E. Ozbay "The Effect of $In_xGa_{1-x}N$ Back-barriers on the Dislocation Densities in $Al_{0.31}Ga_{0.69}N/AlN/GaN/In_xGa_{1-x}N/GaN$ Heterostructures (0.05 $\leq x \leq 0.14$)" Cur. Appl. Phys. **13**, 224 (2013).
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ADVISING

PhD

- **3** E. Kutlu, (Ankara University, Institute of Science, Physics Engineering), 2018- present. Second Advisor.
- 2 P. Narin, (Gazi University, Institute of Science, Physics), 2015 present. Advisor.
- 1 G. Atmaca, (Gazi University, Institute of Science, Physics), Investigations of Low-field Transport and Hot-electron Transport in Passivated AlGaN/GaN HEMTs with Si₃N₄ 2013 2018. Advisor.

MSc

- **12** K. B. Sönmez, (Gazi University, Institute of Science, Advanced Technologies), RF Magnetron Sputter System and Passive Circuit Element Resistor Production and Characterization 2016 2019. Advisor.
- 11 M. T. Haliloğlu, (Gazi University, Institute of Science, Advanced Technologies), Back Side Via Hole Etching Application of SiC for GaN-based Field Effect Transistors 2016 2019. Advisor.
- **10** O. Omeroglu, (Gazi University, Institute of Science, Physics), Investigation of the Electronic Properties of Zn, Cd and Hg-doped Graphene Sheets with Ab-Initio Methods, 2016 2018. Advisor.
- 9 R. Ibrahem, (Gazi University, Institute of Science, Physics), Investigation of Electronic and Optical Properties of Wurtzite MgZnO with First Principles Calculations, 2016 2018. Advisor.

- **8** M. Ozturk, (Gazi University, Institute of Science, Physics), Electrical Characteristics and Scattering Analysis of Ultrathin Barrier GaN-Based High Electron Mobility Transistors, 2015 2018. Advisor.
- 7 J. M. M. J. Al-Abbas, (Gazi University, Institute of Science, Physics), Simulation and optimation of GaN-based ultrathin barrier high electron mobility transistors, 2014 2016. Advisor.
- **6** E. Kutlu, (Gazi University, Institute of Science, Physics), Investigation of the effects of Cadmium Doping on Electronic and Optical Properties of Graphene Nanoribbons, 2014 2016, Advisor.
- **5** A. F. Kuloglu, (Gazi University, Institute of Science, Physics), Investigation of Electronic Properties of Pa-terminated Graphene Nanoribbons, *2010-2012*. Advisor.
- **4** G. Atmaca, (Gazi University, Institute of Science, Physics), Numerical Investigation of the 2-Dimensional Carriers in AlQN/AlN/GaN-Based (Q=Ga, In) Transistors with Multi-Quantum Well Back-Barriers, 2010-2012. Advisor.
- **3** K. Elibol, (Gazi University, Institute of Science, Physics), Investigation of Magnetoconductivity and Surface Properties of Exfoliated and Epitaxially Grown Graphene Samples, 2010-2012. Advisor.
- 2 G. Karakoc, (Gazi University, Institute of Science, Physics), Investigating the Electron Transport Properties of AlInN/AlN/(InGaN)/GaN Heterostructures with InGaN Quantum Wells. 2009-2012. Advisor.
- 1 C. Gunes, (Gazi University, Institute of Science, Physics), Electron and magnetotransport investigation of two dimensional electron gas in ultrathin barrier GaN-based heterostructures. 2009-2012. Advisor.

PERSONAL INFORMATION AND OTHER EXPERIENCE

Birth date: September 12th, 1979 Social Status: Married and have a son.

2018-2020 CEO, Biarsis Ltd. Company manufacturing UV-Vis Spectrometers and light

sources. Successful acquisition of company is completed at September 2020,

http://www.biarsis.com/, Ankara, Turkey.

2010-2011 Completed the <u>one-year full-time long</u> military service as Assistant Professor

Air Defence Second Lieutenant at Turkish Army Forces, 8. Corps, Air

Defence Battalion which is located at Ercis, Van, Turkey.

-End of CV-

Last update: November 5th, 2020.

Hereby, I am confirming that all information listed on this CV is correct at this date.